

Disordered Hubbard model in $d = \infty$

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We investigate the effects of static, diagonal disorder in the $d = \infty$ Hubbard model by treating the dynamical effects of local Hubbard correlations and disorder on an equal footing. This is achieved by a proper combination of the iterated perturbation theory and the coherent potential approximation. Within the paramagnetic phase, we find that the renormalized Fermi liquid metal phase of the pure Hubbard model is stable against disorder for small disorder strengths. With increasing disorder, strong resonant scattering effects destroy low-energy Fermi liquid coherence, leading to an *incoherent* metallic non-FL state off half-filling. Finally, for large enough disorder, a *continuous* transition to the Mott-Anderson insulating phase occurs. The nature of the non-FL metallic phase, as well as the effects of the low energy coherence (incoherence) on optical conductivity and electronic Raman spectra, are considered in detail.

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I. INTRODUCTION

Interest in doped transition metal oxides, a longstanding problem of interest, has been renewed by discovery of non-Fermi liquid behavior observed in the normal state of the high- T_c cuprates, as well as certain other transition metal and rare-earth compounds.¹ In most cases, the non-Fermi liquid anomalies are observed on doping the Mott-Hubbard insulator, a process that is achieved by carrier doping. In real systems, carrier doping is brought about by chemical substitution, a process that simultaneously introduces *disorder* on some length scale. Given this, the electrons “feel” different local environments, and it is physically meaningful to speak only of *disorder averaged* quantities. Calculations carried out on models like the pure Hubbard model represent a homogeneous system, and so fail to capture fully the effects of doping. This suggests that a proper description of such doped materials should include the combined effects of correlations and disorder on an equal footing.

Actually, the one-band Hubbard model with static, diagonal disorder has already been the subject of a few studies.^{2,3} Janiš *et al.*² have studied the effects of site-diagonal disorder on the stability of the half-filled Mott-Hubbard antiferromagnet in detail, using the QMC algorithm to “solve” the $d = \infty$ Hubbard model. Miranda *et al.*³ have considered localization effects in the conduction band DOS and their effects on the distribution of the Kondo temperature, $P(T_K)$, and the resulting non-FL behavior in Kondo alloys. Dobrosavljevic *et al.*³ have considered the role of *off-diagonal* disorder in local moment formation in disordered metals, while Sarma *et al.*⁴ investigated the effects of disorder in the $d = \infty$ Hubbard model in a simple way to study the s.p spectral function; they have also applied their approach to compute the angle-integrated photoemission spectra in $SrTiO_{3-\delta}$, and have demonstrated that the experimental features are reproduced quite well. However, their approach involves treating the effects of disorder by a simple weight-

ing procedure⁴ that is reminiscent of the earlier known virtual crystal approximation for alloys⁵. More recently, Mutou⁴ has used the same treatment for incorporating disorder in the Hubbard model in $d = \infty$. It is known that the VCA is valid for small impurity concentration, and does not interpolate correctly between the weak- and the strong scattering limits, where one has to deal with resonant scattering. In the latter case, a T -matrix approach is more suitable. Indeed, it is known from studies of *non-interacting*, disordered systems that the so-called coherent-potential approximation (CPA) solves the Anderson disorder problem exactly in $d = \infty$.⁶ The effect of disorder in the paramagnetic, strongly correlated FL metallic phase of the $d = \infty$ Hubbard model within a framework valid for all parameter regimes (disorder strength, interaction strength and filling) has not yet been considered.

In this paper, we consider the effects of strong correlations (via the local Hubbard U) and static, diagonal disorder in the *metallic*, paramagnetic state of the $d = \infty$ Hubbard model. Consequently, disorder induced Anderson localization cannot be accessed within our technique, and we will be interested in the effects of disorder-induced strong scattering on the correlated metallic phase away from half-filling.

A naive analysis might lead one to conclude that, at least at low energies, and in $d = \infty$, disorder would have qualitatively the same effects in a free ($U = 0$) system and in an *interacting* Fermi system on a lattice. One might argue that local correlations act to renormalize the bare energy scales, keeping the Fermi liquid correspondence intact, and disorder would then have qualitatively the same effects as in the free ($U = 0$) case. This reasoning, however is not obvious for reasons pointed out by Janiš *et al.*² With strong, local correlations, a M-I transition is possible in a pure Hubbard model. It is known that this transition is characterized by a transfer of dynamical spectral weight over large energy scales, a feature that is completely absent in non-interacting models. In

the $d = \infty$ Hubbard model, for e.g., spectral weight is transferred over large energy scales as the temperature is lowered through the lattice Kondo scale, T_K^{latt} ,⁶ giving rise to nontrivial effects in thermodynamics, and in dc and ac transport. This makes emergence of qualitatively new behaviors (which have no analogues in the free system) possible, and hence a consistent framework to study correlations and disorder on an equal footing is in order.

In this work, we aim to study the combined effects of correlations and static, site-diagonal disorder in the quantum paramagnetic phase of the $d = \infty$ Hubbard model. The questions we want to answer are:

(1) Is there an instability of the strongly correlated Fermi liquid metal to an incoherent, non-Fermi liquid metal as the disorder is increased, and, if so, what strength of disorder is required?

(2) What is the character of this non-Fermi liquid state, if it exists?

(3) What is the critical disorder strength required to drive this metallic state insulating? (notice that this is more appropriately termed, “Anderson-Mott insulator” following²).

(4) What is the effect of the above scenario (if it exists) on the dynamical responses, e.g., on the optical conductivity, electronic Raman lineshape, etc?

In this work, we aim to provide answers to these questions within the dynamical mean field theory (DMFT, $d = \infty$) of strongly correlated fermionic systems. In the next section, we set up the formalism to study the combined effects of correlations and disorder exactly in $d = \infty$. This is followed by a detailed discussion of the role of site-diagonal disorder in a strongly correlated FL metal, and on the nature of the incoherent metallic state at intermediate disorder strength. In particular, the qualitatively different results we obtain (in comparison to⁴) are emphasized, and the differences are shown to arise from the fact that the CPA, in contrast to VCA, treats the weak- and strong scattering limits equally well.⁵ Lastly, as an application, we describe how the formalism presented here can be fruitfully applied to study the interplay of correlations (competition between atomic and itinerant tendency) and static, diagonal disorder on the ac conductivity, and the electronic Raman lineshape of doped transition metal compounds. The manifestation of the combined effects of the local Hubbard interaction and local, static disorder on the dynamical charge response of doped, strongly correlated metals has not been considered to date, and ours are the first attempt in this direction.

II. MODEL AND LOCAL SPECTRAL DENSITY IN $D = \infty$

We start with the one-band Hubbard model (HM) with static, site-diagonal disorder on a hypercubic lattice in $d = \infty$,

$$H = -t \sum_{\langle i,j \rangle, \sigma} (c_{i\sigma}^\dagger c_{j\sigma} + h.c.) + U \sum_i n_{i\uparrow} n_{i\downarrow} + \sum_{i\sigma} v_i n_{i\sigma} \quad (1)$$

where the disorder potentials v_i are specified by a given probability distribution. We restrict ourselves to *microscopic* disorder, and so work with a binary-alloy distribution for disorder; explicitly,

$$P(v_i) = (1 - x)\delta(v_i) + x\delta(v_i - v). \quad (2)$$

In other words, upon doping, a fraction x of the sites have an additional local potential v for an electron (or hole) hopping onto that site. Given this, the carriers experience different local environments in the course of their hopping, and the physically sensible object is the disorder-averaged local Green function (GF), $\langle G_{ii}(\omega) \rangle_c$, where $\langle .. \rangle_c$ means a disorder average. In $d = \infty$, all interesting dynamical information is entirely contained in $\langle G_{ii}(\omega) \rangle_c$, the computation of which is the central aim of this section.

As stated above, the problem of interacting, disordered fermions requires a simultaneous consideration of both on an equal footing. To see how one proceeds, notice that the model, eqn.(1) is exactly soluble in $d = \infty$ by CPA when $U = 0$, and approximately by the IPT⁶ when $v = 0$. This is a reliable technique to solve the $d = \infty$ problem, and yields results in good agreement with numerical studies in the paramagnetic phase. To treat disorder and interactions simultaneously requires a suitable extension, either from the $U = 0$ limit, where the disorder problem is first solved exactly, and the interactions are then considered, using the CPA DOS as an input to the interacting model, or the disorder-free Hubbard model is first solved by IPT in $d = \infty$, and the IPT GF serves as an input to the CPA procedure. In what follows, we take the latter route. In principle, both starting points should yield the same final result in a fully selfconsistent treatment of interactions and disorder on the same footing. To be consistent, consideration of the competition between interactions in the metallic phase and static disorder requires a fully selfconsistent procedure, which we describe in what follows.

We start by writing down the local effective action for the impurity model with site-diagonal disorder;²

$$S_{eff}[i] = - \sum_{\sigma} \int_0^{\beta} d\tau \int_0^{\beta} d\tau' c_{i\sigma}^\dagger(\tau) g_{\sigma}^{-1}(\tau, \tau') c_{i\sigma}(\tau') \\ + U \int_0^{\beta} n_{i\uparrow}(\tau) n_{i\downarrow}(\tau) \quad (3)$$

where the Weiss fn., describing the dynamics on the rest of the lattice is given by,

$$g_{\sigma}^{-1}(\tau, \tau') = \delta(\tau - \tau')(-v_i - \partial_{\tau}) - t^2 \int dv_i P(v_i) G_{ii\sigma}(v_i, \tau, \tau') \quad (4)$$

with the integral over v_i representing the disorder average. In the above, G_{ii} is the fully interacting local Green fn. of the lattice model. To solve the effective problem, one has to first solve the interacting problem, followed by a disorder average, and link these up in a proper selfconsistent way. In this work, the interaction part is treated via selfconsistent iterated perturbation theory (IPT) away from half-filling.⁷ We used this technique as it yields the correct Fermi liquid metallic state, and gives results in very good agreement with numerical studies in the quantum paramagnetic regime, which we consider here. The interplay between local correlations and static disorder is studied by a combination of the IPT with the CPA, as described below.

Step 1 The disorder-free Hubbard model, eqn.(1), is “solved” in $d = \infty$ by iterated perturbation theory at and off half-filling.⁷ This maps the lattice problem onto an effective one-body problem describing the propagation of renormalized fermion quasiparticles in a complex effective medium, as described by a local self-energy, $\Sigma(\omega)$. This procedure is known to yield the correct FL behavior in the quantum paramagnetic phase of the $d = \infty$ Hubbard model, and gives results in good agreement from those obtained from exact diagonalization studies. The effective one-body Hamiltonian now is formally written as,

$$H_{eff} = \sum_{\mathbf{k}} [\epsilon_{\mathbf{k}} + \Sigma(\omega)] c_{\mathbf{k}\sigma}^\dagger c_{\mathbf{k}\sigma} \quad (5)$$

To treat the effects of disorder, we follow the philosophy of the CPA, which entails removing one site from the effective medium, and replacing it with the actual local potential, v_i . The *effective* local potential that scatters the electrons (holes) is now $V_i = v_i - \Sigma(\omega)$, with $\Sigma(\omega)$ to be determined selfconsistently from the CPA condition. This condition requires that the additional scattering produced by the effective potential vanish on the average; this is equivalent to the requirement that the configuration-averaged T -matrix vanish, $\langle T_{ii}[\Sigma(\omega)] \rangle_c = 0$. In $d = \infty$, the usual procedure is to map the lattice problem onto this single-site problem supplemented with a selfconsistency condition linking this site to the rest of the lattice. The single-site hamiltonian is,

$$H = \sum_{\mathbf{k}} [\epsilon_{\mathbf{k}} + \Sigma(\omega)] c_{\mathbf{k}\sigma}^\dagger c_{\mathbf{k}\sigma} + \sum_{i, \mathbf{k}, \sigma} t_{\mathbf{k}} (c_{\mathbf{k}\sigma}^\dagger c_{i\sigma} + h.c) + \sum_{i\sigma} (v_i - \Sigma(\omega)) n_{i\sigma} \quad (6)$$

for the problem with disorder.⁶

Step 2 The local spectral density, computed for the pure HM in $d = \infty$, is used as an input to the CPA procedure, which computes a new self energy which takes account of disorder induced scattering processes exactly in $d = \infty$.^{5,6} Given the IPT DOS, $\rho(\omega)$, from Step 1, the CPA yields the following eqns for the corrected self-energy and the disorder averaged GF:

$$\Sigma_c(\omega) = xv + \frac{v^2 x(1-x)}{\omega - v(1-x) - \mathcal{A}(\omega)} \quad (7)$$

and,

$$\langle G_{ii}(\omega) \rangle_c = \frac{1-x}{\omega - \mathcal{A}(\omega)} + \frac{x}{\omega - v - \mathcal{A}(\omega)} \quad (8)$$

where x is the concentration of dopants, created by alloying or chemical substitution, and $\mathcal{A}(\omega)$ is the effective dynamical (Weiss) field for the model with disorder and/or Hubbard on-site correlations. A complete derivation of the above formulae is given in the appendix for convenience.

Step 3 The full, disorder averaged GF, $\langle G_{ii}(\omega) \rangle_c$, is used as a new input to the IPT routine that recomputes the local self-energy of the interacting problem with the modified GFs from the zero-order iteration that involves steps (1+2). The modified IPT propagator is then fed back into the CPA routine. The updated GF is then fed back into the IPT routine and the process is iterated to convergence.

Step 4 At each stage, the Luttinger sum rule, $n_\sigma = \int_{-\infty}^{\mu} \rho_\sigma(\omega) d\omega$, is satisfied to a high accuracy. The iteration procedure described above describes the *full* fermion propagator dressed by interactions (IPT) and disorder scattering (CPA) and the selfconsistency procedure ensures that the mutual interplay of correlations and disorder is treated consistently in $d = \infty$.

All dynamical quantities of interest in the quantum paramagnetic metallic regime are obtained from $G_{ii}(\omega)$. The electrical transport properties for the DHM can be computed from the spectral density. The optical conductivity for the DHM can be computed from the local GFs, since vertex corrections in the Bethe-Salpeter eqn for the conductivity vanish identically in $d = \infty$.⁶ The relevant eqn is,

$$\sigma_{xx}(i\omega) = \frac{1}{i\omega} \int \rho_0(\epsilon) \sum_{i\nu} G(\epsilon, i\nu) G(\epsilon, i\omega + i\nu) \quad (9)$$

Moreover, in the same approximation, the Raman intensity lineshape is simply related to the optical conductivity as,⁸

$$I_{xx}(\omega) = \frac{\omega}{1 - e^{-\beta\omega}} \text{Re} \sigma_{xx}(\omega) \quad (10)$$

The complete magneto-optical response of the DHM in the quantum para-metallic state can also be readily computed in a way identical to that used for the pure HM.⁹

III. RESULTS IN $D = \infty$

We now proceed to discuss our results. In our calculations, we employed a gaussian unperturbed DOS,⁶ and $U/D = 3.0$ (D is the free bandwidth). We used the IPT

off $n = 1$ as a reliable approximation to treat the correlation part exactly in $d = \infty$. The IPT gives results in excellent agreement with exact diagonalization studies,⁶ and we have checked that all desirable FL properties are reproduced in our numerics. We restricted ourselves to the paramagnetic metallic phase throughout. We varied the disorder strength in the range $0 \leq v \leq U$ at fixed n , and repeated our calculations for each $n = 1, 0.9, 0.8$ to get a clear picture of the combined effects of (correlations + disorder) and band-filling.

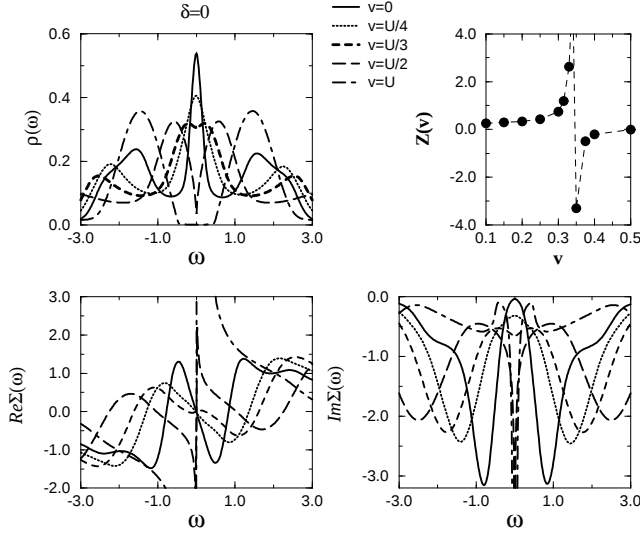


FIG. 1. Local spectral density, and real and imaginary parts of the s.p self-energy for the disordered Hubbard model in $d = \infty$.

Fig. 1 shows the result of the calculation for the local DOS of the DHM in $d = \infty$. For $v = 0$, the DOS shows all the characteristic features⁶ of the strongly correlated FL metal (also shown up in the self-energy, the real and imaginary parts of which are also shown in fig. 1).

The dotted line in fig. 1 shows the local spectral density and the self-energy for small ($v = U/4$) disorder strength. As expected, the central FL peak is broadened by disorder, and $\text{Im}\Sigma(\omega) = -a - b\omega^2$ acquires a finite value at the Fermi surface due to disorder scattering. Notice that the height of the central peak has decreased from its non-interacting value for $v = U/4$, and so Luttinger’s theorem is not satisfied (notice that the Luttinger sum rule, fixing the value of the chemical potential, is still satisfied, but Luttinger’s theorem breaks down, in the sense that a sharp Fermi surface no longer exists). This is the consequence of the $\mathbf{k}$ -space degeneracy arising from the introduction of disorder. Nevertheless, the self-energy shows a behavior characteristic of a *dirty* Fermi liquid. We notice that an analogous situation would arise in a treatment of the disorder in the Born approximation (or its self-consistent versions), and refer to this metallic state as a disordered Fermi liquid. At $v = U/3$, however, one sees the emergence of a qualitatively new behavior in fig. 1 (dashed line); a pseudogap develops in a *continuous* way

in the local DOS, and $\Sigma(\omega)$ has a *qualitatively* new behavior. $\text{Im}\Sigma(\omega)$ has a *minimum* at μ , and $\text{Re}\Sigma(\omega)$ has a positive slope, invalidating the quasiparticle picture. We refer to this phase as the *incoherent* metallic phase. With increasing disorder strength, the pseudogap in the DOS deepens, and the shallow minimum in $\text{Im}\Sigma(\omega)$ develops into a sharp peak at μ (fig. 1 with the long dashed line). Finally, at $v = U$, a clear gap develops at μ , and the incoherent metallic state undergoes a *continuous* transition to an “Anderson-Mott” insulator. Similar trends are observed off $n = 1$, as shown in fig. 2 for $n = 0.9$.

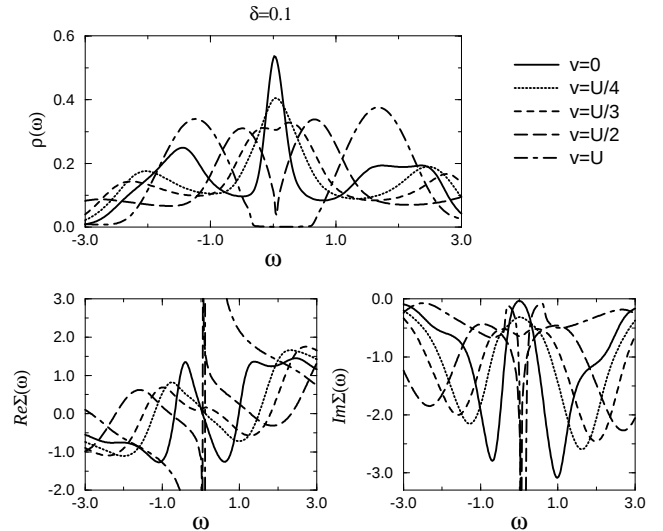


FIG. 2. Local spectral density, and real and imaginary parts of the s.p self-energy for the disordered Hubbard model in $d = \infty$.

The quasiparticle residue, $Z(\mu)$, calculated as $Z(\mu) = 1/(1 - F(\mu))$, with $F(\mu) = d[\text{Re}\Sigma(\omega)]/d\omega|_{\omega=\mu}$, illustrates the FL- non FL “transition” in a clearer way (fig. 1). With $U/D = 3.0$, $n = 1$, the Fermi liquid is stable upto $v/U = (v/U)_c \simeq 0.31$. For $v > v_c$, we see that $Z(\mu) > 1$, or even negative, invalidating the very concept of coherent FL quasiparticles. A similar behavior of $Z(\mu)$ is obtained within the CPA treatment of the non-interacting, disordered model (see appendix). This illustrates how the FL metal is destroyed *continuously* with increasing disorder before the Anderson-Mott insulating phase is approached around $v/U \simeq 1$. This insulating phase results from the complete splitting of the DOS for large v , and happens in a way similar to that in usual CPA. It is not caused by Anderson localization, which cannot be accessed in $d = \infty$, as is known. Thus, for small values of v , the “FL metal” survives; for intermediate v , we have shown that the metallic state is *not* a Fermi liquid; it is rather an incoherent metal. This incoherent metal is unstable to a Mott-Anderson insulator beyond a certain $v = v_c$. These results are very different from those obtained in the treatment of the non-interacting, disordered model using CPA. Indeed, in this case, the incoherent metal phase develops for *any* value of the dis-

order. To see this, we use the CPA eqns for the selfenergy with $U = 0$, whereby $G(\omega) = G_c(\omega)$. The CPA yields,

$$\Sigma_c(\omega) = xv + \frac{v^2 x(1-x)}{\omega - v(1-x) + iD^2\pi\rho_0(\mu)} \quad (11)$$

as shown in the appendix. With a positive definite ρ_0 , $\text{Re}\Sigma_c(\omega)$ has a positive slope near μ (see appendix), and so the metallic state is not a FL. The above illustrates the importance of treating both correlations and disorder on an equal footing, and shows that the actual behavior in such systems is quite different from those with only interactions (no disorder), or those with only disorder (no interactions).

The above results are also quite different from those obtained from a VCA treatment of disorder.⁴ To see this, we have repeated the calculation carried out by Mutou, and have observed that the incoherent, non-FL pseudogap metal phase never sets in, no matter how strong the disorder. This is a direct consequence of the fact that the VCA cannot treat resonant scattering correctly (intermediate v) while it is known that the CPA works equally well for *all* values of disorder.² In fact, our results (fig. 1, fig. 2) are completely consistent with those of Mutou⁴ when v is small ($v = U/4$), in which case, the CPA as well as the VCA give results in accordance with a perturbative treatment of disorder.

IV. TRANSPORT PROPERTIES OF THE DHM IN $D = \infty$

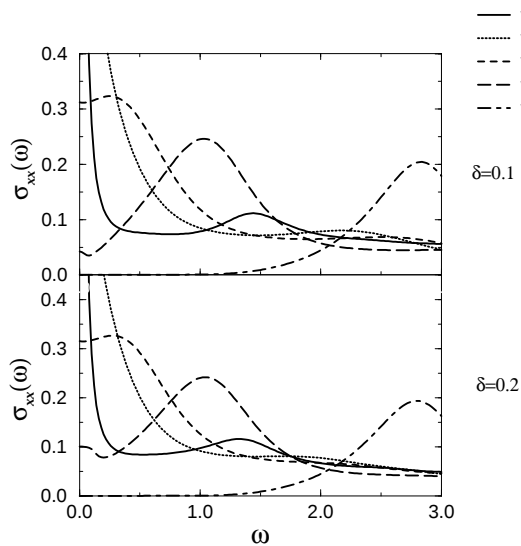


FIG. 3. Optical conductivity of the disordered Hubbard model in $d = \infty$ as a fn. of disorder strength for two different band-fillings, $n = 0.9, 0.8$.

Knowledge of the full disorder Green function is a sufficient input for a controlled computation of transport properties in $d = \infty$. This is because vertex corrections

drop out in the Bethe-Salpeter eqn. for the two-particle propagator, for e.g. for the conductivity, and the corresponding susceptibility is just the convolution of the *full* GFs.⁶ Using the formulae given in Section II, we have computed the optical conductivity and the electronic Raman scattering lineshape for the DHM.

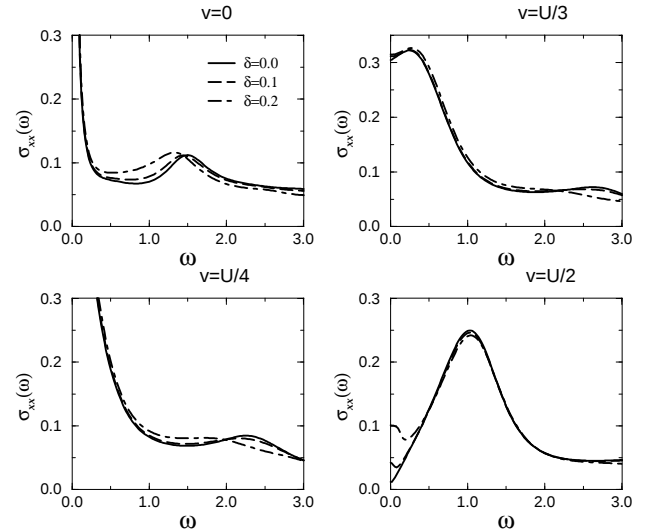


FIG. 4. Optical conductivity of the disordered Hubbard model in $d = \infty$ as a fn. of band-filling for different disorder strengths: $v/U = 0, 1/4, 1/3, 1/2$.

The changes in the local spectral density as a function of v and filling for a given U/D are reflected in the optical spectra. fig. 3 shows the calculated optical conductivity for $U/D = 3.0$, $n = 0.9, 0.8$ and for different disorder strengths. The solid line corresponds to the pure Hubbard model; we see that all expected features are reproduced in good agreement with earlier work.⁶ In particular, the “Drude” peak at $\omega = \mu$, the mid-IR peak around $U/2$, which corresponds to transitions between the lower-Hubbard band and the central FL resonance, and the high-energy peak corresponding to transitions between the Hubbard bands, are all reproduced well. As expected from the evolution of the DOS, small disorder, $v = U/4$, broadens the “Drude” peak, and smoothens out the mid-IR and high energy features, while preserving a FL response (dotted line). With $v = U/3$, however, all semblance of the Drude peak has disappeared completely, and the pseudogap formation in the DOS is clearly reflected in $\sigma(\omega)$. The dashed line ($v = U/3$) therefore represents the optical response characteristic of an incoherent non-FL metal (since the DOS at μ is finite). Notice that the mid-IR feature is progressively broadened and shifted to higher energies with increasing v as seen for $v = U/2$ (long dashed line). Finally, the onset of the Mott-Anderson insulating phase is clearly reflected in the appearance of a threshold feature in the optical response. This scenario is only slightly modified as a function of band-filling, as shown in fig. 3.

It is known that the optical response of the Hubbard

model⁸ shows up the dramatic transfer of spectral weight from high- to low energy on hole doping, a characteristic of strongly correlated systems. A very interesting, related observation is that the $\sigma_{xx}(\omega)$ curves for different hole doping cross at a single point, ω_c , the so-called *isosbestic* point. Similar features are observed for the DHM as a fn. of hole-doping, as seen in fig. 4. We observe that the $\sigma_{xx}(\omega)$ curves now seem to cross at *two* points as a fn. of doping. This seems to be true for all disorder strengths, and clearly warrants a closer examination. Heuristically, we can understand the crossing of the curves as arising from the high- and low-frequency behavior of the charge susceptibility;⁸ a microscopic understanding of the two crossing points is, however, a harder task.

The qualitatively different behavior of the optical response for varying disorder strengths can be understood in terms of the coherent (incoherent) part of the low-frequency spectral density. At zero or weak disorder, the Green fn. still is that characteristic of a Fermi liquid (real or complex pole structure), and $\sigma_{xx}(\omega)$ shows a “Drude” peak at $\omega = \mu$. With increasing disorder, one is in the resonant scattering regime, all semblance of the quasiparticle behavior is destroyed, and the GF is characterized by a branch-cut behavior. The difference in the spectra as a fn. of disorder is then a consequence of the fact that the response, which is caused by the action of the current operator (which has non-zero matrix elements between lower-Hubbard band states) does not create well-defined elementary excitations as v is increased. Within the $d = \infty$ ideas used here, the coherent response is the manifestation of the collective band Kondo effect for zero or weak disorder, while the incoherent response for larger v is a consequence of the suppression of this coherence scale by disorder-induced strong scattering.

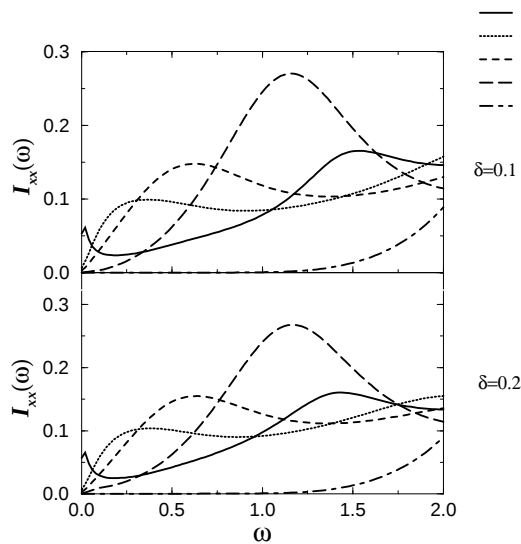


FIG. 5. Electronic Raman scattering lineshape for the disordered Hubbard model in $d = \infty$ as a fn. of disorder for two values of band-filling, $n = 0.9, 0.8$.

In $d = \infty$, the electronic Raman scattering lineshape

can be directly obtained from the optical conductivity, as remarked above. In light of the above discussion, we expect a sharp electron-hole peak, characteristic of coherent particle-hole response in a FL, for $v = 0$, and a disorder induced broadening of this feature for small $v = U/4$. For larger v , we expect a completely incoherent lineshape characteristic of the non-FL pseudogap metal state ($v = U/3, U/2$). This is indeed what we observe in our calculations (fig. 5) and is related to the fact that the collective particle-hole model is overdamped by disorder-induced resonant scattering in this regime. The evolution of the Raman spectrum with increasing disorder is then understood as follows. The stress tensor (whose fluctuations are measured in the Raman lineshape), which connects the eigenstates of the Hubbard Hamiltonian, creates well defined elementary excitations at low energy in a FL, giving a sharp peak at low energy, while in the incoherent metal regime, the Green function has a branch cut, and the action of the stress tensor does not create well-defined elementary excitations, resulting in a continuum response at low energy.

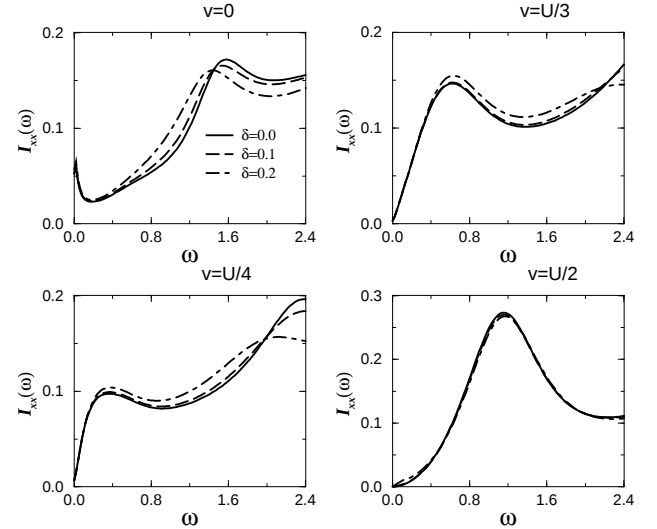


FIG. 6. Electronic Raman scattering lineshape for the disordered Hubbard model in $d = \infty$ as a fn. of band-filling for different disorder strengths, $v/U = 0, 1/4, 1/3, 1/2$.

The transfer of spectral weight with doping is also revealed in the Raman lineshapes (fig. 6), and is understood directly in terms of the evolution of $\sigma_{xx}(\omega)$ as a fn. of doping. In fig. 6, we show the Raman lineshapes as a fn. of doping for four different disorder strengths, $v = 0, U/4, U/3$ and $v = U/2$. In spite of the different nature of the metallic state for the first two disorder values, the isosbestic point in $I_{xx}(\omega)$ is clearly revealed, seemingly independent of details of the low-energy spectra.

In conclusion, we have considered the role of static, site-diagonal disorder in the quantum paramagnetic phase of the $d = \infty$ Hubbard model. We have devised a formalism that captures the interplay of dynamical local

correlations inherent in the Hubbard model and doping-induced disorder on an equal footing. This is achieved by a proper extension of the IPT off half-filling, which has been shown to work well in the paramagnetic phase of the $d = \infty$ Hubbard model, by combining it (selfconsistently) with the CPA, which is known to yield the exact solution of the Anderson disorder problem in $d = \infty$. We have shown that the FL metal is stable against *small* disorder ($v = U/4$), and that strong repeated scattering effects at higher disorder values destroys the FL coherence, giving rise to an incoherent pseudogap metal phase. At a critical v , this phase becomes unstable to a Mott-Anderson insulating phase. We have also considered the effects of the interplay between correlations in the FL metallic state and disorder in $d = \infty$ on the optical and Raman response, and have shown how low-energy coherence (incoherence) is manifested in the dynamical charge response of correlated, disordered systems in this limit. Lastly, consideration of effects akin to Anderson localization require an extension of the approach to include non-local correlations, or extensions along the lines of Miranda *et al.*³ We plan to study such effects in the future.

V. APPENDIX

In this appendix, we review briefly the CPA in the interaction-free case ($U = 0$). The CPA essentially involves (i) replacing the actual disorder problem by an *effective* one-body problem, where the electrons now move in a dynamical (complex) effective medium. (ii) One now removes this complex potential (self energy, $\Sigma(\omega)$) from one local site, i , and replaces it with the actual local potential, v_i . The additional effective potential seen by an electron is now $V_i = v_i - \Sigma(\omega)$. For a binary alloy disorder, $P(v_i) = (1 - x)\delta(v_i) + x\delta(v_i - v)$, one needs to average additionally over disorder. The site-diagonal T -matrix corresponding to this additional effective scattering potential V_i , after configuration averaging, is set to zero in the CPA condition:⁵

$$\frac{(1 - x)(-\Sigma(\omega))}{1 + \Sigma(\omega)G(\omega)} + \frac{x(v - \Sigma(\omega))}{1 - (v - \Sigma(\omega))G(\omega)} = 0 \quad (12)$$

Solving for the self-energy, $\Sigma(\omega)$, using $G^{-1}(\omega) = \omega - \Sigma(\omega) - \mathcal{A}(\omega)$ gives the eqns. (7) and (8) used in the text.

Next, we show that the unusual feature of the $Z(\mu)$ vs v (fig. (1)) can be understood analytically in the CPA as well. In fact, as we show below, the CPA in the case with $U = 0$ always leads to $Z(\mu) > 1$, showing that the metallic state is never a Fermi liquid. Choosing the unperturbed DOS to be a lorentzian with half-width D , one can show⁶ that $\mathcal{A}(\omega) = -iD$. The selfconsistent eqns. now reduce to a single algebraic eqn. for the self-energy, giving exactly eqn. (11) in the text with $\rho_0(\mu) = 1/D\pi$. The resulting real part of the self-energy has a *positive* slope at low energy, giving $Z(\mu) = [1 - (v/2D)^2]^{-1}$, which is never FL-like.

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⁴ D. D. Sarma *et al.*, Europhys. Lett. **36**, 307 (1996). see also T. Mutou, Phys. Rev. B **60**, 2268 (1999). Mutou uses the IPT at half-filling to solve the correlation part, and the VCA to include the effects of static disorder. In contrast, we have used the IPT off half-filling and the CPA (which works well for *all* impurity concentrations and disorder strengths) to include the interplay between correlations and disorder away from $n = 1$. This is more physical, since chemical substitution, which creates disorder, also introduces carriers, taking the system away from half-filling.

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